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Micro Commercial Components (MCC)
MMBT2222AT-TP

For any questions, you can email us directly:
sales@integrated-circuit.com

Micro Commercial Components
20736 Marilla Street Chatsworth
CA 91311
Phone: (818) 701-4933
Fax: (818) 701-4939

MMBT2222AT

NPN General Purpose Amplifier

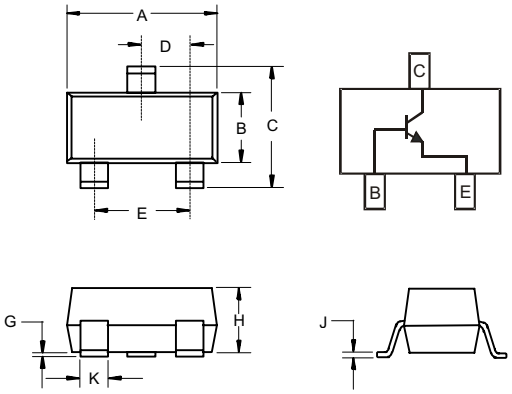
Features

- Halogen free available upon request by adding suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix designates RoHS Compliant. See ordering information)
- Capable of 150mWatts of Power Dissipation
- Operating and Storage Junction Temperatures -55℃ to 150℃
- Collector Current: 0.6A
- Epoxy meets UL 94 V-0 flammability rating
- Moisure Sensitivity Level 1
- Marking:1P

Electrical Characteristics @ 25°C Unless Otherwise Specified

Symbol	Parameter	Min	Max	Units
OFF CHARACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage* (I_C=10mAdc, I_B=0)	40		Vdc
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage (I_C=10μAdc, I_E=0)	75		Vdc
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage (I_E=10μAdc, I_C=0)	6.0		Vdc
I_{CBO}	Collector Cut-off Current (V_{CB}=70Vdc, I_E=0)		100	nAdc
I_{CEO}	Collector Cutoff Current (V_{CE}=35Vdc, I_B=0)		100	nAdc
I_{EBO}	Emitter Cut-off Current (V_{EB}=3Vdc, I_C=0)		100	nAdc
ON CHARACTERISTICS				
h_{FE}	DC Current Gain* (I_C=0.1mAdc, V_{CE}=10Vdc) (I_C=1.0mAdc, V_{CE}=10Vdc) (I_C=10mAdc, V_{CE}=10Vdc) (I_C=150mAdc, V_{CE}=10Vdc) (I_C=150mAdc, V_{CE}=10Vdc) (I_C=500mAdc, V_{CE}=10Vdc)	35 50 75 100 50 40	300	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage (I_C=150mAdc, I_B=15mAdc) (I_C=500mAdc, I_B=50mAdc)		0.3 1.0	Vdc
$V_{BE(sat)}$	Base-Emitter Saturation Voltage (I_C=150mAdc, I_B=15mAdc) (I_C=500mAdc, I_B=50mAdc)		1.2 2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS				
f_T	Current Gain-Bandwidth Product (I_C=20mAdc, V_{CE}=20Vdc, f=100MHz)	300		MHz
C_{obo}	Output Capacitance (V_{CB}=10Vdec, I_E=0, f=100kHz)		8.0	pF
SWITCHING CHARACTERISTICS				
t_d	Delay Time	(V_{CC}=30Vdc, V_{BE}=0.5Vdc I_C=150mAdc, I_{B1}=15mAdc)	10	ns
t_r	Rise Time		25	ns
t_s	Storage Time	(V_{CC}=30Vdc, I_C=150mAdc I_{B1}=I_{B2}=15mAdc)	225	ns
t_f	Fall Time		60	ns

SOT-523



DIMENSIONS					
	INCHES		MM		
DIM	MIN	MAX	MIN	MAX	NOTE
A	.059	.067	1.50	1.70	
B	.030	.033	0.75	0.85	
C	.057	.069	1.45	1.75	
D	.020 Nominal		0.50Nominal		
E	.035	.043	0.90	1.10	
G	.000	.004	.000	.100	
H	.028	.031	.70	0.80	
J	.004	.008	.100	.200	
K	.010	.014	.25	.35	

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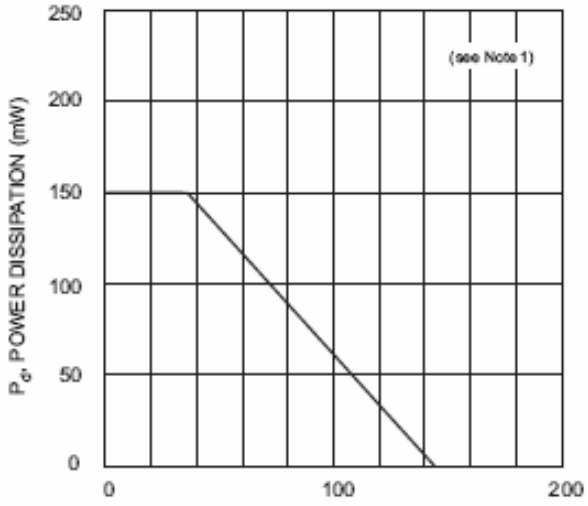

Fig. 1, Power Derating Curve

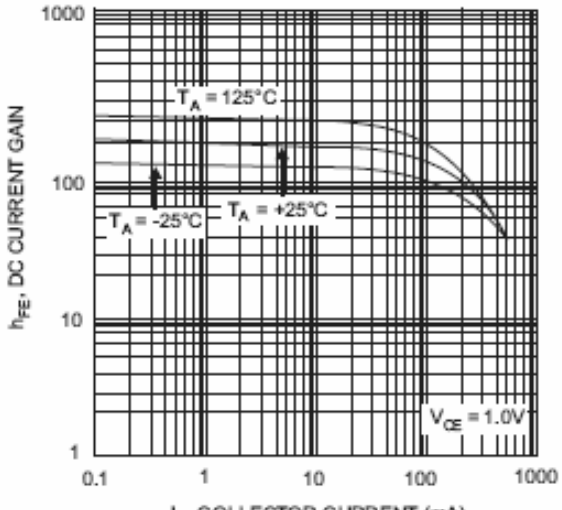

Fig. 2 Typical DC Current Gain vs Collector Current

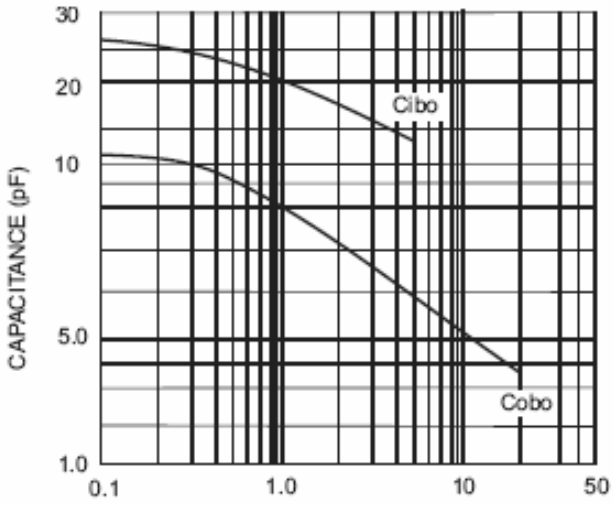

Fig. 3 Typical Capacitance

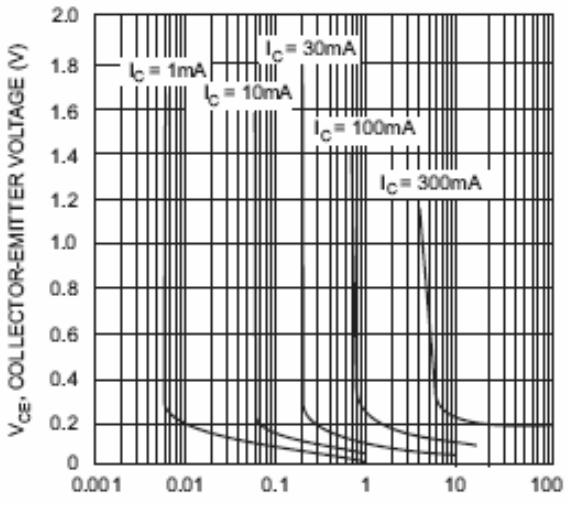

Fig. 4 Typical Collector Saturation Region

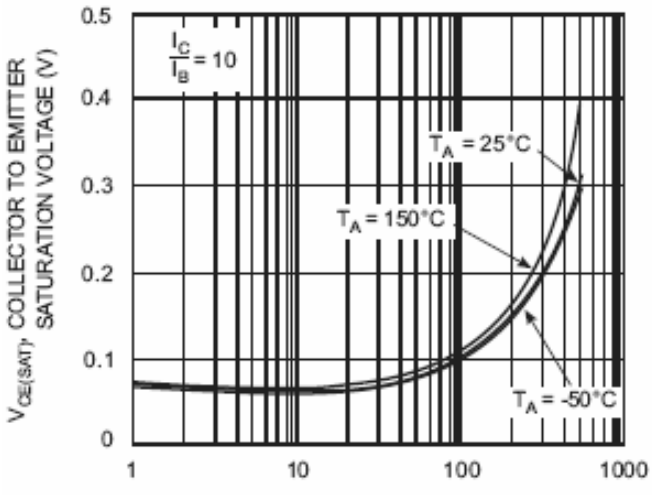

Fig. 5 Collector Emitter Saturation Voltage vs. Collector Current

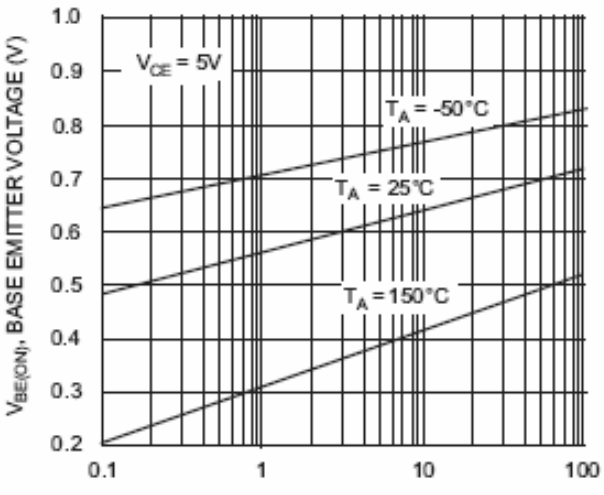

Fig. 6 Base Emitter Voltage vs. Collector Current

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Ordering Information :

Device	Packing
Part Number-TP	Tape&Reel;3Kpcs/Reel

Note : Adding "-HF" suffix for halogen free, eg. Part Number-TP-HF